

RJH60F3DPK

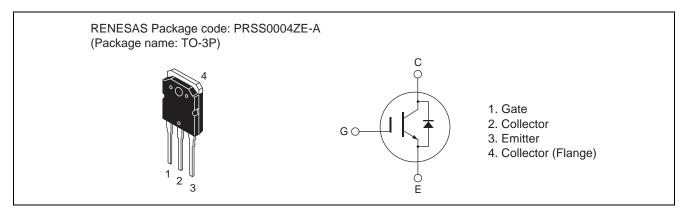
Silicon N Channel IGBT High Speed Power Switching

R07DS0199EJ0200 Rev.2.00 Dec 01, 2010

Features

- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.4$ V typ. ($I_C = 20$ A, $V_{GE} = 15$ V, Ta = 25°C)
- Built in fast recovery diode in one package
- Trench gate and thin wafer technology
- High speed switching $t_f = 92 \text{ ns typ. (at } I_C = 30 \text{ A}, \ V_{CE} = 400 \text{ V}, \ V_{GE} = 15 \text{ V}, \ Rg = 5 \ \Omega, \ Ta = 25 ^{\circ}C, \ inductive \ load)$

Outline



Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to Emitter voltage		V _{CES}	600	V
Gate to Emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25 °C	Ic	40	А
	Tc = 100 °C	Ic	20	Α
Collector peak current		ic(peak) Note1	80	А
Collector to emitter diode forward peak current		i _{DF} (peak) Note2	80	A
Collector dissipation		Pc	178.5	W
Junction to case thermal impedance (IGBT)		θј-с	0.7	°C/W
Junction to case thermal impedance (Diode)		θј-с	2.0	°C/W
Channel temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

2. PW $\leq 5~\mu s,$ duty cycle $\leq 1\%$

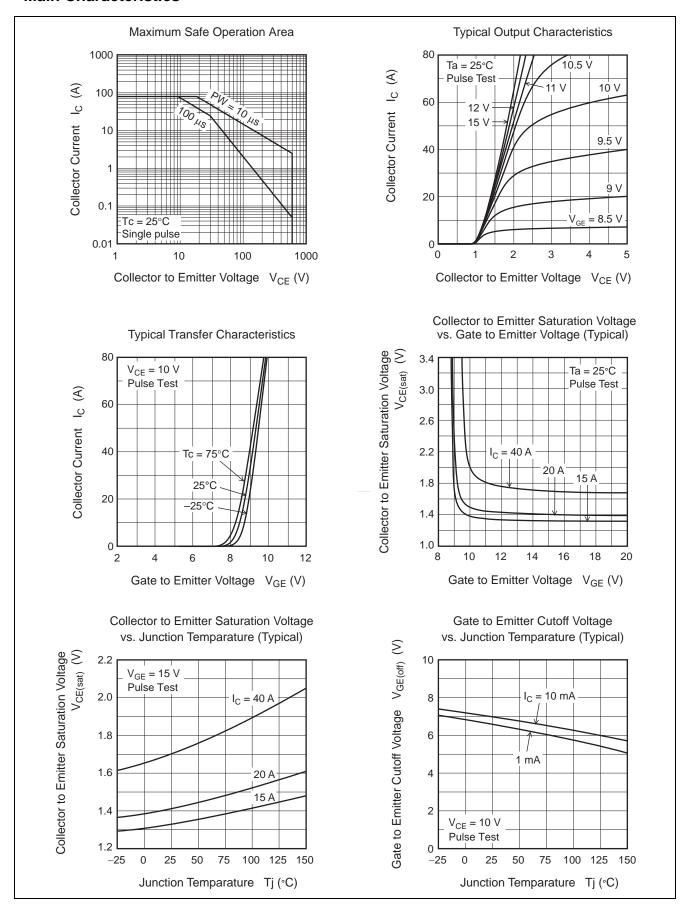
Electrical Characteristics

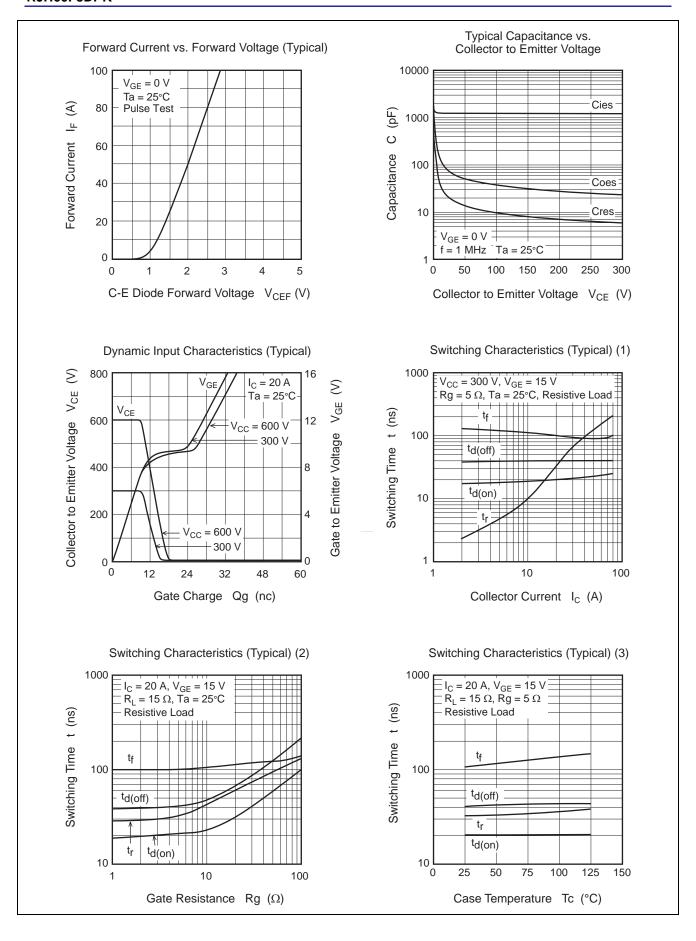
(Tj = 25°C)

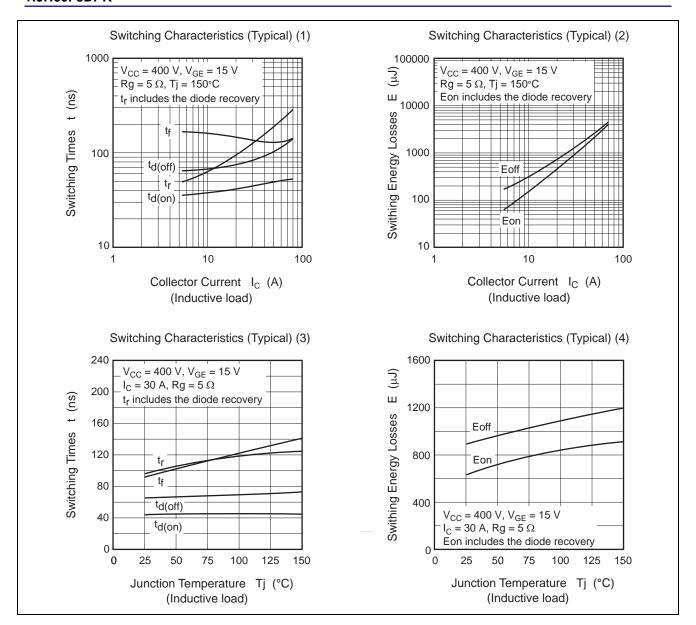
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current	I _{CES}	_	_	100	μΑ	$V_{CE} = 600V, V_{GE} = 0$	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	4	_	8	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.4	1.82	V	$I_C = 20 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
		_	1.6	_	V	$I_C = 40 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1260	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	73	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres	_	21	_	pF	f = 1 MHz	
Switching time	t _{d(on)}	_	44	_	ns	I _C = 20 A, Resistive Load	
	t _r	_	96	_	ns	V _{CC} = 300 V	
	t _{d(off)}	_	65	_	ns	$V_{GE} = 15 \text{ V}$	
	t _f	_	92	_	ns	$Rg = 5 \Omega^{Note3}$	
C-E diode forward voltage	V _{ECF1}	_	1.6	2.1	V	I _F = 20 A ^{Note3}	
	V _{ECF2}	_	1.8	_	V	I _F = 40 A Note3	
C-E diode reverse recovery time	t _{rr}	_	140	_	ns	I _F = 20 A	
						$di_F/dt = 100 A/\mu s$	

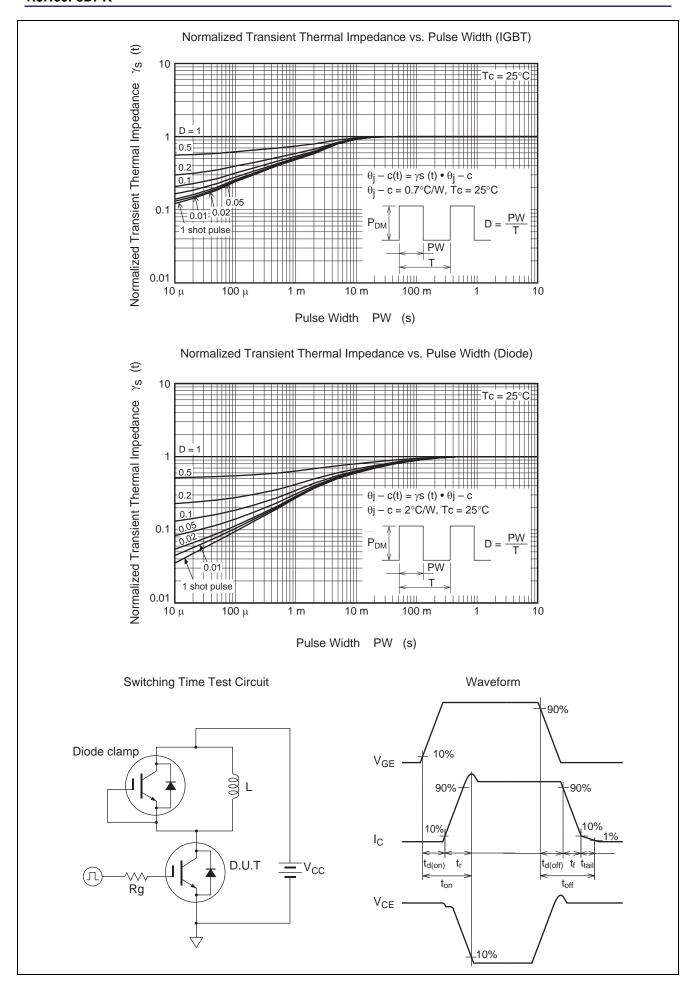
Notes: 3. Pulse test

Main Characteristics

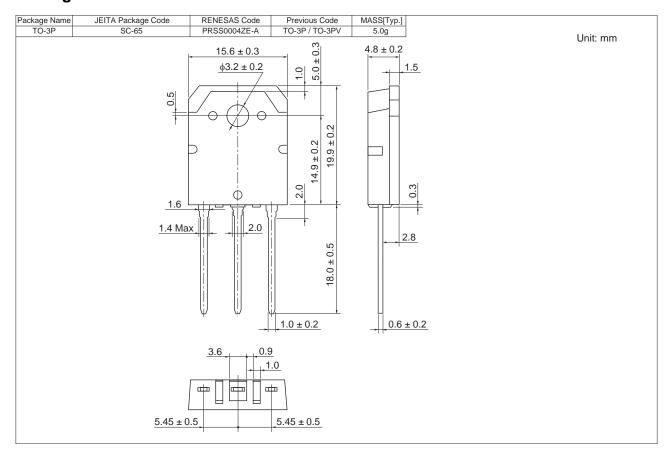








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60F3DPK-00-T0	360 pcs	Box (Tube)

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